NSN 5961-00-773-7927



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-773-7927 **Inclosure Material:** Metal **Overall Length:** 1.040 inches **Overall Diameter:** 0.650 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Internal Junction Configuration:** Pnp **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.250 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-base, emitter open and 15.0 emitter to base voltage, static, collector open and 30.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 1.5 watts small-signal input power, common-collector absolute **Transfer Ratio:** 32.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a

Demilitarization: No

Unit Of Measure:

NSN 5961-00-773-7927 Transistor - Page 2 of 2



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